

【DESCRIPTION】

【Invention Title】

CONTROL METHOD OF DRIVING FREQUENCY OF PULSED VARIABLE
FREQUENCY RF GENERATOR

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【Technical Field】

[1] The present disclosure relates to a pulsed variable frequency RF generator and, more particularly, to a control method of a frequency of a pulse-type variable frequency RF generator for frequency tuning impedance matching.

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【Background Art】

[2] Plasma is used in semiconductor manufacturing processes such as an etching process and a deposition process. A radio-frequency (RF) generator generates plasma by applying a high-power RF signal to a load of a chamber. The generated plasma processes a surface of a substrate to have a desired shape or deposits a thin film on the substrate.

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[3] In this case, the high-power RF signal is transmitted to the load of the chamber to generate plasma. To this end, impedance between the RF generator and the load of the chamber should be matched to transfer power of a signal without reflection. As a rapid impedance matching technique, the RF generator adjusts a driving frequency of an RF signal to perform impedance matching. In a frequency variable impedance matching method, impedance matching is usually performed at a level of several milliseconds (msec).

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[4] With the advance in semiconductor manufacturing process, an RF signal, applied to a load of a chamber, may be a pulsed

RF signal having an intensity modulated at a constant period. Conventionally, the pulsed RF signal is turned on/off at a pulse frequency of several hundred Hz to several kHz lower than a driving frequency of several MHz to several tens MHz. As the
5 pulse frequency is increased to reduce an on-time period of several milliseconds or less, rapid control of a driving frequency of the RF signal is required for pulse impedance matching. When the pulse frequency increases to several kHz or higher, the on-time period decreases to 1 msec or less.
10 Therefore, it is difficult to complete impedance matching due to insufficient time to adjust the driving frequency of the RF signal. As a result, the plasma is unstable.

【Disclosure】

15 **【Technical Problem】**

[5] An aspect of the present disclosure is to provide a control method of a driving frequency of a pulsed RF generator and an impedance matching method.

20 **【Technical Solution】**

[6] According to an aspect of the present disclosure, a pulsed variable frequency RF generator according to an example embodiment provides RF power to a load as a pulse of an ON-time period T_{ON} and an OFF-time period T_{OFF} , which are alternate,
25 and includes a control loop varying a driving frequency in the ON-time period T_{ON} . A control method of a driving frequency of the pulsed variable frequency generator includes varying a

driving frequency $f(n,m)$ in an ON-time period $T_{ON}(n)$ of an n -th pulse; predicting a driving frequency of an ON-time period $T_{ON}(n+1)$ of an $(n+1)$ -th pulse using admittance of the ON-time period $T_{ON}(n)$ of the n -th pulse; and providing an RF output
5 of the pulsed variable frequency RF generator as the predicted driving frequency $f(n+1,1)$ in the ON-time $T_{ON}(n+1)$ of the $(n+1)$ -th pulse. $f(n,m)$ is a driving frequency in an m -th processing number in the ON-time period $T_{ON}(n)$ of the n -th pulse, n denotes a sequence number of a pulse, m is a positive
10 integer of 1 to q , and m denotes an index indicating the processing number of the control loop for varying a driving frequency in the ON-time period T_{ON} .

[7] In an example embodiment, the varying a driving frequency $f(n,m)$ in an ON-time period $T_{ON}(n)$ of an n -th pulse may include
15 a first step of measuring an RF current signal I and an RF voltage signal V at an output terminal of the pulsed variable frequency RF generator in the ON-time period $T_{ON}(n)$ of the n -th pulse; a second step of calculating impedance Z_i and a reflection coefficient Γ_i at the output terminal of the pulsed variable
20 frequency RF generator by using the RF current signal I and the RF voltage signal V in the ON-time period $T_{ON}(n)$ of the n -th pulse, a phase-shifted reflection coefficient Γ' reflecting a phase caused by a transmission line, and phase-shifted admittance y' ; and a third step of selecting an increasing or
25 decreasing direction of the driving frequency of the pulsed

variable frequency RF generator depending on a sign of an imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient in the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse and varying the driving frequency. The first step, the second step,
5 and the third step may be repeated until the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse is finished.

[8] In an example embodiment, the predicting a driving frequency of an ON-time period $T_{\text{ON}}(n+1)$ of an $(n+1)$ -th pulse using admittance of the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse
10 may include: linearly fitting an imaginary part of the phase-shifted admittance y' in an n -th ON-time period $T_{\text{ON}}(n)$ with respect to the driving frequency; and setting a frequency corresponding to a point, in which the imaginary part of the phase-shifted admittance y' is zero (0), as a predicted driving
15 frequency $f(n+1,1)$ of an ON-time period $T_{\text{ON}}(n+1)$ of an $(n+1)$ -th pulse.

[9] In an example embodiment, a prediction driving frequency $f(n+1,m=1)$ of the ON-time period $T_{\text{ON}}(n+1)$ of the $(n+1)$ -th pulse may be given as follows:

20 [10] $f(n+1,m=1) = f(n,m=q) - b'(n,m=q) [df/db']$

[11] $df/db' = [f(n,m=q) - f(n,m=r)] / [b'(n,m=q) - b'(n,m=r)],$

[12] where $f(n,m=r)$ denotes a driving frequency at a predetermined r -th processing number in the ON-time period $T_{\text{ON}}(n)$ of an n -th pulse, $b'(n,m=r)$ denotes susceptance which
25 is the imaginary part of the phase-shifted admittance y' at the

predetermined r -th processing number of the ON-time period $T_{ON}(n)$ of the n -th pulse, $f(n, m=q)$ denotes a driving frequency at the last processing number in the ON-time period $T_{ON}(n)$ of the n -th pulse, and $b'(n, m=q)$ denotes susceptance which is the
5 imaginary part of the admittance y' of the last processing number q of the ON-time period $T_{ON}(n)$ of the n -th pulse.

[13] In an example embodiment, r may be a positive integer of 3 to $q-1$.

[14] In an example embodiment, the control method may further
10 include: determining an optimal condition for impedance matching using the phase-shifted reflection coefficient Γ' . The optimal condition may be determined by an absolute value $|\Gamma'|$ of the phase-shifted reflection coefficient or a magnitude of the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection
15 coefficient Γ' . When the determined condition is the optimal condition, the first step of measuring an RF current signal I and an RF voltage signal V at an output terminal of the pulsed variable frequency RF generator may be performed after increasing an index m indicating a processing number for
20 variation of a driving frequency. When the determined condition is not the optimal condition, the third step of varying the driving frequency may be performed.

[15] In an example embodiment, in the third step of selecting an increasing or decreasing direction of the driving frequency
25 of the pulsed variable frequency RF generator depending on a

sign of an imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient in the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse and varying the driving frequency, a driving frequency may be increased when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a positive value, and a driving frequency may be decreased when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a negative value.

[16] In an example embodiment, a variation amount of the driving frequency in the n -th ON-time period $T_{\text{ON}}(n)$ may depend on an absolute value of the phase-shifted reflection coefficient or an absolute value of the imaginary part of the phase-shifted reflection coefficient.

[17] In an example embodiment, the control method may further include: changing a reactance value of a variable reactance element of an impedance matching network, which is disposed between the pulsed variable frequency RF generator and the load and includes at least two variable reactance elements, to set a real part $\text{Re}(Z_i)$ of the impedance in the load direction at the output terminal of the pulsed variable frequency RF generator as characteristic impedance of a transmission line.

[18] In an example embodiment, the control method may further include a plasma stabilizing step, including an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate, without

variation of the driving frequency of the pulsed variable frequency RF generator.

[19] According to another aspect of the present disclosure, a pulsed variable frequency RF power system according to an example embodiment includes a pulsed variable frequency RF generator configured to supply RF power to a load as a pulse of an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. The pulsed variable RF generator includes an impedance sensing unit disposed at an output terminal of the pulsed variable frequency RF generator in an n-th ON-time period $T_{ON}(n)$ to sense an RF current signal and an RF voltage signal; an impedance processing unit configured to calculate impedance Z_i and a reflection coefficient Γ_i by using the RF current signal and the RF voltage signal at the output terminal of the pulsed variable frequency RF generator, a phase-shifted reflection coefficient Γ' by a transmission line between the load and the pulsed variable frequency RF generator, and phase-shifted admittance y' converted from the phase-shifted reflection coefficient Γ' in the n-th ON-time period $T_{ON}(n)$; a driving frequency prediction unit configured to predict a next ON-time period $T_{ON}(n+1)$ using the phase-shifted admittance y' with respect to a driving frequency; a driving frequency control unit configured to receive the predicted driving frequency and set the predicted driving frequency as a start driving frequency of the next ON-time period $T_{ON}(n+1)$ and to controls a driving

frequency using the phase-shifted reflection coefficient Γ' ;
a pulse generator configured to generate a pulse signal and
divide the ON-time period T_{ON} and the OFF-time period T_{OFF}
and to provide the pulse signal to the driving frequency
5 prediction unit and the driving frequency control unit; and an
RF amplifier configured to amplify a sinusoidal wave of a
driving frequency of the driving frequency control unit.

[20] In an example embodiment, the driving frequency
prediction unit may linearly fit an imaginary part of
10 phase-shifted admittance y' with respect to a driving frequency,
in an n -th ON-time period $T_{ON}(n)$ to set a frequency,
corresponding to a point in which the imaginary part of the
phase-shifted admittance y' is zero, as a prediction driving
frequency.

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【Advantageous Effects】

[21] As described above, a control method of a driving
frequency of a pulsed variable frequency RF generator according
20 to an example embodiment may complete impedance matching at
higher speed than a conventional frequency control method and
may operate at an optimal frequency at which a reflected wave
is significantly reduced even when the impedance matching is
not completed.

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【Description of Drawings】

[22] FIG. 1 illustrates an example of performing impedance matching by conventional frequency tuning or frequency variation.

5 [23] FIG. 2 illustrates an example of performing impedance matching by conventional frequency tuning or frequency variation.

[24] FIG. 3 illustrates an example of performing impedance matching by conventional frequency tuning or frequency
10 variation.

[25] FIG. 4 is a circuit diagram of a pulsed variable frequency RF generator and a load according to an example embodiment of the present disclosure.

[26] FIG. 5 is a Smith chart illustrating impedance when
15 viewing a load at an output terminal of the pulsed variable frequency RF generator in FIG. 4.

[27] FIG. 6 is a circuit diagram of a pulsed variable frequency RF generator and a load according to another example embodiment of the present disclosure.

20 [28] FIG. 7 is a flowchart illustrating an operation of the pulsed variable frequency RF generator in FIG. 6.

[29] FIG. 8 illustrates a pulsed RF signal, a pulse generator pulse state signal, and a driving frequency of the pulsed variable frequency RF generator in FIG. 6.

[30] FIG. 9 illustrates admittance, depending on a driving frequency, on a Smith chart.

[31] FIG. 10 is an imaginary part depending on a driving frequency.

5 [32] FIG. 11 illustrates variation of a driving frequency depending on operating time of a control loop.

[33] FIG. 12 illustrates an imaginary part of admittance depending on a driving frequency according to another example embodiment of the present disclosure.

10 [34] FIG. 13 illustrates variation of a driving frequency depending on operating time of a control loop in FIG. 12.

[35] FIG. 14 is a Smith chart illustrating a load and variation in impedance Z' of an impedance matching network according to another example embodiment of the present disclosure.

15 [36] FIG. 15 is a graph illustrating susceptance, shown on the Smith chart in FIG. 14, depending on a driving frequency.

[37] FIG. 16 illustrates a pulse sequence according to another example embodiment of the present disclosure.

【Best Mode for Invention】

20 [38] FIG. 1 illustrates an example of performing impedance matching by conventional frequency tuning or frequency variation.

[39] Referring to FIG. 1, a variable frequency RF power supply transfers RF power to a load through an ON-time period T_{ON} and
25 an OFF-time period T_{OFF} which are alternate. When the ON-time

period T_{ON} is sufficient to be longer than several milliseconds, a driving frequency of the variable frequency RF power supply starts at a start driving frequency f_{start} in each ON-time period T_{ON} to complete impedance matching at a matching frequency f_{match} within a predetermined time. Frequency tuning is normally performed within an ON-time period of a single pulse.

[40] FIG. 2 illustrates an example of performing impedance matching by conventional frequency tuning or frequency variation.

[41] Referring to FIG. 2, a variable frequency RF power supply transfers RF power to a load through an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. When the ON-time period T_{ON} is insufficient to be shorter than 50 μ sec, a driving frequency of the variable frequency RF power supply starts at a start driving frequency f_{start} in each ON-time period T_{ON} and does not reach a matching frequency f_{match} , and thus, impedance matching may not be completed.

[42] FIG. 3 illustrates an example of performing impedance matching by conventional frequency tuning or frequency variation.

[43] Referring to FIG. 3, a variable frequency RF power supply transfers RF power to a load through an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. When the ON-time period T_{ON} is insufficient to be shorter than 50 μ sec, a driving

frequency of the variable frequency RF power supply starts at a first starting driving frequency f_{l_start} in a first on-time period T_{ON} and does not reach a matching frequency f_{match} within the first on-time period, and thus, impedance matching
5 may not be completed. However, in a second ON-time period T_{ON} , a final frequency of the first ON-time period may be set to be a second start driving frequency to perform impedance matching while successively varying the driving frequency in the second ON-time period. As a result, the frequency varies in an i -th
10 ON-time period and reaches the matching frequency f_{match} to complete impedance matching.

[44] However, such an impedance matching method requires a plurality of pulses to complete frequency variable impedance matching. Accordingly, there is a need for a high-speed and
15 efficient impedance matching method of a pulsed variable frequency RF generator.

[45] In a frequency tuning impedance matching method according to an example embodiment, a start driving frequency and an RF out signal, set by a user, are analyzed to vary a driving
20 frequency. Specifically, a next frequency may be predicted using a susceptance, an imaginary part of admittance measured in an n -th pulse, to rapidly complete impedance matching or to rapidly reach an optimal frequency.

[46] Embodiments of the present disclosure will now be
25 described below more fully with reference to accompanying

drawings. The present disclosure may, however, be embodied in different forms and should not be constructed as limited to the embodiments set forth herein. Rather, these embodiments are provided so that this disclosure will be thorough and complete,
5 and will fully convey the scope of the present invention to those skilled in the art.

[47] FIG. 4 is a circuit diagram of a pulsed variable frequency RF generator and a load according to an example embodiment of the present disclosure.

10 [48] FIG. 5 is a Smith chart illustrating impedance when viewing a load at an output terminal of the pulsed variable frequency RF generator in FIG. 4.

[49] Referring to FIGS. 4 and 5, a pulsed variable frequency RF generator 110 transfers RF power to a load 140 through an
15 impedance matching network 130 and a transmission line 120. Impedance when viewing the impedance matching network 130 and the load 140 is Z' . Impedance when viewing the transmission line 120, the impedance matching network 130, and the load 140 at an output terminal N1 of the pulsed variable frequency RF
20 generator 110 is Z_i . The first impedance Z_i may be converted into first admittance ($Y_i=1/Z_i$), and the second impedance Z' may be converted into a second admittance Y' . The second admittance Y' may be expressed by a normalized admittance ($y'=Z_0 Y'=g'+jb'$), where Z_0 denotes characteristic impedance of the

transmission line 120, g' denotes conductance, and b' is susceptance.

[50] An impedance matching point is a point, at which a reflection coefficient Γ is zero, as the origin of a Smith chart.

5 When a real part of the second impedance Z' , viewed at the input terminal N2 of the impedance matching network 130, is fixed to 50 ohms, a conductance circle with $g'=1$ is a circle with the origin and P_{sc} as a diameter. When a driving frequency of the pulsed variable frequency RF generator 110 is increased, a point
10 P_3 of the Smith chart rotates clockwise along a conductance circle with $g'=1$. When the driving frequency of the pulsed variable frequency RF generator 110 is decreased, a point P_2 of the Smith chart rotates clockwise along the conductance circle with $g=1$.

15 [51] The first impedance Z_i further has a phase difference ϕ , caused by the transmission line 120, as compared to the second impedance Z' . The conductance circle with $g'=1$ rotates clockwise for the second impedance Z' on the Smith chart. The phase difference ϕ is in proportion to a driving angular
20 frequency ω and a length d of the transmission line 120 and is in inverse proportion to speed c of an electromagnetic wave. The characteristic impedance of the transmission line 120 is Z_0 .

[52] When an imaginary part of a second reflection coefficient
25 Γ' has a positive value, the driving frequency is increased such

that the imaginary part moves to the origin of the Smith chart along a minimum path to complete impedance matching. Meanwhile, when the imaginary part of the second reflection coefficient Γ' has a negative value, the driving frequency is decreased such
5 that the imaginary part moves to the origin of the Smith chart along the minimum path to complete impedance matching.

[53] A point P_1 , present on the conductance circuit with $g=1$, rotates clockwise for a first impedance Z_i when the driving frequency is increased and rotates counterclockwise for the
10 first impedance Z_i when the driving frequency is decreased.

[54] Accordingly, a reflection coefficient Γ_i may rotate by the phase difference ϕ to easily determine increase or decrease in the driving frequency for frequency tuning impedance matching. Specifically, the point A may be converted into a
15 point B by phase shift. Thus, the increase or decrease in the drive frequency may be determined depending on a sign of the imaginary part of the reflection coefficient Γ' .

[55] When the driving frequency is increased at a position P_1 corresponding to the first impedance Z_i , the impedance is moved
20 clockwise along a circle, passing through the position P_1 , depending on the impedance characteristics. When the driving frequency is decreased, the impedance is moved counterclockwise. When the drive frequency is tuned based on such a principle and the impedance moves to an origin on the
25 Smith chart, impedance matching is completed.

[56] To complete impedance matching at the shortest distance from the position P1, it is advantageous to decrease a frequency when the position P1 is disposed above a line passing through the origin on the Smith chart and the center of a characteristic
5 circle of the position P1 and to increase a frequency when the position P1 is disposed below the line.

[57] To easily find a shortest trajectory, when an angle ϕ is provided to the conductance circle with $g=1$, a line, passing through the center of the circle and the center of the Smith
10 chart, matches an X axis (an axis of the real part of the reflection coefficient). Accordingly, an optimal trajectory direction may be determined depending on whether an imaginary component of the reflection coefficient G' is positive or negative. The reflection coefficient of the position P1 is
15 multiplied by a complex number having a phase of ϕ and a size of 1. Accordingly, it is advantageous to increase the driving frequency in the P3 position where an imaginary component of the reflection coefficient Γ' is positive. In addition, it is advantageous to decrease the driving frequency in a position
20 P2 where the imaginary component of the reflection coefficient Γ' is negative.

[58] FIG. 6 is a circuit diagram of a pulsed variable frequency RF generator and a load according to another example embodiment of the present disclosure.

[59] FIG. 7 is a flowchart illustrating an operation of the pulsed variable frequency RF generator in FIG. 6.

[60] FIG. 8 illustrates a pulsed RF signal, a pulse generator pulse state signal, and a driving frequency of the pulsed variable frequency RF generator in FIG. 6.

[61] FIG. 9 illustrates admittance, depending on a driving frequency, on a Smith chart.

[62] FIG. 10 is an imaginary part depending on a driving frequency.

10 [63] FIG. 11 illustrates variation of a driving frequency depending on operating time of a control loop.

[64] Referring to FIGS. 6 to 11, a pulsed variable frequency RF power system 100 includes a pulsed variable frequency RF generator 110 and an impedance matching network 130 disposed between the pulsed variable frequency RF generator 110 and a load 140. The pulsed variable frequency RF generator 110 provides RF power to the load 140 in an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. The impedance matching network 130 includes at least two variable reactance elements C1 and C2. A reactance value of the variable reactance element of the impedance matching network 130 is changed to adjust impedance in a direction of the load 140.

[65] The pulse type variable frequency RF generator 110 includes an impedance sensing unit 115, an impedance processing unit 111, a driving frequency prediction unit 117, a driving

frequency control unit 113, a pulse generator 116, and an RF amplifier 114. The pulsed variable frequency RF generator 110 varies a driving frequency to operate at an impedance matching frequency or an optimal frequency at high speed.

5 [66] The impedance sensing unit 115 is disposed at an output terminal N1 of the pulsed variable frequency RF generator 110 in an n-th ON-time period $T_{ON}(n)$ to sense an RF current signal I and an RF voltage signal V (n being the order of a pulse).

[67] The impedance processing unit 111 calculates impedance
10 Z_i and a reflection coefficient Γ_i at the output terminal N1 of the pulsed variable frequency RF generator 110 in the n-th ON-time period $T_{ON}(n)$ by using the RF current signal I and the RF voltage signal V, a phase-shifted reflection coefficient Γ' by a transmission line 120 between the load 140 and the pulsed
15 variable frequency RF generator 110, and phase-shifted admittance y' converted from the phase-shifted reflection coefficient Γ' .

[68] The driving frequency prediction unit 117 predicts a driving frequency of a next ON-time period $T_{ON}(n+1)$ using the
20 phase-shifted admittance y' depending with respect to a driving frequency measured in the n-th ON-time period $T_{ON}(n)$.

[69] The driving frequency control unit 113 sets the predicted driving frequency as a start driving frequency of the next ON-time period $T_{ON}(n+1)$ and controls a driving frequency using
25 the phase-shifted reflection coefficient Γ' .

[70] The pulse generator 116 generates a pulse signal to divide the ON-time period T_{ON} and the OFF-time period T_{OFF} and provides the pulse signal to the driving frequency prediction unit 117 and the driving frequency control unit 113.

5 [71] The RF amplifier 114 amplifies a sinusoidal wave at a driving frequency of the driving frequency control unit to output an RF signal.

[72] The load 140 may be an electrode, which generates capacitively-coupled plasma, or an antenna which generates
10 inductively-coupled plasma. The load 140 may be mounted inside or outside a chamber in which a semiconductor process is performed. The load 140 may generate pulse plasma in synchronization with the pulse signal. The driving frequency may be several MHz to several tens of MHz. The pulse frequency
15 may range from several kHz to several tens of kHz. An ON-Duty Ratio of the RF pulse may range from several percent to several tens of percent. The ON-time period T_{ON} may be less than 50 μ sec. In detail, the ON-time period T_{ON} may be 100 μ sec or less.

20 [73] The impedance matching network 130 may be classified into various types depending on connection methods of variable reactive elements. As an example, the impedance matching network 130 includes a first variable capacitor C1, connected in series to the load 140, and a second variable capacitor C2
25 connected in parallel to the first variable capacitor C1 and

the load 140 connected in series. The impedance matching network 130 may be an L-type, an inverted L-type, a T-type, or a π -type impedance matching network. The impedance matching network 130 may be operated to perform impedance matching when
5 the impedance matching, performed by tuning the driving frequency of the pulsed variable frequency RF generator 110, fails.

[74] The impedance sensing unit 115 measures the RF current signal I and the RF voltage signal V at the output terminal N1
10 of the pulsed variable frequency RF generator 110 in a direction of the load 140. The RF current signal I and the RF voltage signal V may be sampled at a higher sampling rate than the driving frequency for a sampling time longer than a period of the driving frequency to be converted into a digital signal to be provided
15 to the impedance processing unit 111.

[75] The impedance processing unit 111 may calculate the impedance Z_i and/or the reflection coefficient Γ_i at the output terminal N1 of the pulsed variable frequency RF generator 110 using the RF current signal I and the RF voltage signal V. In
20 addition, the impedance processing unit 111 may compensate for a phase difference ϕ caused by the length d of the transmission line 120. Specifically, the reflection coefficient Γ_i may be converted into a phase-shifted reflection coefficient Γ' when viewing the load 140 at the input terminal N2 of the impedance
25 matching network 130 and is converted as follows:

[76] Equation 1

$$[77] \Gamma' = \Gamma_i e^{j\varphi}$$

$$[78] \varphi = \omega d / c$$

[79] where φ denotes a phase difference, d denotes a length
5 of a transmission line, ω denotes a driving angular frequency,
and c denotes speed of an electromagnetic wave on a transmission
line. The transmission line 120 may be a coaxial cable. The
phase-shifted reflection coefficient Γ' is a reflection
coefficient when viewing the load 140 at the input N2 of the
10 impedance matching network 130.

[80] The impedance processing unit 111 may convert the
phase-shifted reflection coefficient Γ' into phase-shifted
admittance y' . The phase-shifted admittance y' may be given
as follows:

15 [81] Equation 2

$$[82] y' = g' + jb'$$

[83] where g' denotes conductance and b' denotes susceptance.

[84] The driving frequency control unit 113 may receive the
phase-shifted reflection coefficient Γ' . The driving
20 frequency control unit 113 may divide the ON-time period T_{ON}
into a plurality of unit time Δt to vary the driving frequency
every unit time Δt . The unit time Δt may be about 1 usec as
on operating time of a control loop. Thus, the total number
of control loops (q) is $T_{ON}/\Delta t$ (q being a positive integer
25 greater than or equal to 3).

[85] The driving frequency control unit 113 may select increase and decrease directions of the driving frequency, depending on a sign of the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient. Specifically, when the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient has a positive value, the driving frequency may be increased by a frequency variation amount df . Meanwhile, when the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient has a negative value, the driving frequency may be decreased by the frequency variation amount df . The frequency variation amount df may depends on a magnitude of the absolute value $|\Gamma'|$ of the reflection coefficient or a magnitude of the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient. For example, the frequency variation amount df may be in proportion to the magnitude of the absolute value of the reflection coefficient $|\Gamma'|$ or the magnitude of the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient. For example, the driving frequency control unit 113 may not vary the driving frequency when impedance matching is performed with the absolute value $|\Gamma'|$ of the reflection coefficient less than or equal to the threshold value. The driving frequency controller 113 may adjust the frequency variation amount df depending on a degree of the impedance matching.

[86] The driving frequency control unit 113 may use a proportional-integral-derivative control scheme. The driving frequency control unit 113 may output the driving frequency in

the ON-time period T_{ON} and may not output the driving frequency in the OFF-time period T_{OFF} .

[87] The RF amplifier 114 may provide an RF output at the driving frequency. The RF amplifier 114 may be an RF power
5 amplifier. An output of the RF amplifier 114 may be several hundreds of watts to tens of kilowatts.

[88] The pulse generator 116 may provide a pulse signal for identifying the ON-time period T_{ON} and the OFF-time period T_{OFF} to the driving frequency control unit 113 and the driving
10 frequency prediction unit 117. A frequency of the pulse generator 116 may range from several kHz to several tens of kHz. When the driving frequency is in the range of 13.56 MHz, the ON-time period T_{ON} and the OFF-time period T_{OFF} may be respectively about 50 μ sec. An operating time of a control loop
15 or a unit time Δt may be about 1 μ sec.

[89] The driving frequency prediction unit 117 may receive a start frequency f_{start} of a first pulse. In addition, the driving frequency prediction unit 117 may receive a threshold value for determining an optimal condition. In addition, the
20 driving frequency prediction unit 117 may receive a specific number ($m = r$) of a control loop to perform frequency prediction or a hold-off time. The driving frequency prediction unit 117 may receive the phase-shifted admittance y' or the susceptance b' and the driving frequency f . The driving frequency
25 prediction unit 117 may receive the phase-shifted reflection

coefficient Γ' to be compared with the threshold value, and may calculate a prediction driving frequency only when the impedance matching condition is not satisfied.

[90] The driving frequency prediction unit 117 may linearly
 5 fit an imaginary part b' of the phase-shifted admittance y' , depending on a driving frequency in an n -th ON-time period $T_{ON}(n)$, to set a frequency corresponding to a point, in which the imaginary part b' of the phase-shifted admittance y' is zero (0), as a prediction driving frequency.

10 [91] The predicted driving frequency $f(n+1,1)$ of the next ON-time period $T_{ON}(n+1)$ may be given as follows:

[92] Equation 3

$$[93] \quad f(n+1, m=1) = f(n, m=q) - b'(n, m=q) [df/db']$$

$$[94] \quad df/db' = [f(n, m=q) - f(n, m=r)] / [b'(n, m=q) - b'(n, m=r)]$$

15 [95]

[96] where $f(n, m=r)$ denotes a drive frequency at a predetermined r -th processing number in the ON-time period $T_{ON}(n)$ of an n -th pulse, $b'(n, m=r)$ denotes susceptance of the phase-shifted admittance y' at the predetermined r -th
 20 processing number of the ON-time period $T_{ON}(n)$ of the n -th pulse, $f(n, m=q)$ denotes a driving frequency at the last processing number in the ON-time period $T_{ON}(n)$ of the n -th pulse, and $b'(n, m=q)$ denotes susceptance which is the imaginary part of the admittance y' of the last processing number q of
 25 the ON-time period $T_{ON}(n)$ of the n -th pulse. In Equation 3,

r may be a positive integer ranging from 3 to q-1, the total number q of control loops is $T_{ON}/\Delta t$, and q is a positive integer greater than or equal to 3.

[97] Alternatively, the predicted driving frequency $f(n+1,1)$ of the next ON-time period $T_{ON}(n+1)$ may be given as follows:

[98] Equation 4

[99] $f(n+1,m=1) = f(n,m=r) - b'(n,m=r) [df/db']$

[100] $df/db' = [f(n,m=q) - f(n,m=r)] / [b'(n,m=q) - b'(n,m=r)]$

[101]

[102] The driving frequency prediction unit 117 may provide the predicted driving frequency $f(n+1, m=1)$ to the driving frequency control unit 113 to operate at a start driving frequency of an (N+1)-th ON-time period $T_{ON}(n+1)$. Thus, high-speed frequency tuning impedance matching may be completed.

[103] Hereinafter, an impedance matching method of a pulsed variable frequency RF generator will be described.

[104] Returning to FIG. 7, the pulsed variable frequency RF generator 110 according to an example embodiment may provide RF power to the load 140 as a pulse of an ON-time period T_{ON} and an OFF-time period T_{OFF} , which are alternate, and includes a control loop varying a driving frequency in the ON-time period T_{ON} .

[105] An impedance matching method of the pulsed variable frequency RF generator 110 includes varying a driving frequency

$f(n,m)$ in an ON-time period $T_{ON}(n)$ of an n -th pulse (S101),
 predicting a driving frequency of an ON-time period $T_{ON}(n+1)$
 of an $(n+1)$ -th pulse using admittance of the ON-time period
 $T_{ON}(n)$ of the n -th pulse (S131), and providing an RF output
 5 of the pulsed variable frequency RF generator 110 as the
 predicted driving frequency $f(n+1,1)$ in the ON-time $T_{ON}(n+1)$
 of the $(n+1)$ -th pulse (S141). In this case, $f(n,m)$ is a driving
 frequency in an m -th processing number (or a control loop) in
 the ON-time period $T_{ON}(n)$ of the n -th pulse. n denotes a
 10 sequence number of a pulse, m is a positive integer between 1
 and q . The total number q of the control loops is $T_{ON}/\Delta t$. q
 is greater than or equal to 3. m denotes an index indicating
 the processing number of the control loop for varying a driving
 frequency in the ON-time period T_{ON} .
 15 [106] First, a start driving frequency f_{start} of the first
 pulse, a duty ratio of a pulse, a period of the pulse, the total
 number q of control loops in one pulse, an operation time Δt
 of the control loop and an initial value of the index m indicating
 the processing number of the control loop are set (S110).
 20 [107] The step S101 of varying the driving frequency $f(n,m)$ in
 the ON-time period $T_{ON}(n)$ of the n -th pulse includes a first
 step S121, a second step S122 and S123, and a third step S126.
 [108] In step S121, an RF current signal I and an RF voltage
 signal V are measured at the output terminal of the pulse-type
 25 variable frequency RF generator 110 in the ON-time period

$T_{ON}(n)$ of the n -th pulse. The RF current signal I and the RF voltage signal V may be sensed by the impedance sensing unit 115.

[109] In steps S122 and S123, the RF current signal I and the RF voltage signal V are used in the ON-time period $T_{ON}(n)$ to calculate impedance Z_i and a reflection coefficient Γ_i at an output terminal of the pulsed variable frequency RF generator, a phase-shifted reflection coefficient Γ' , and phase-shifted admittance y' . The phase-shifted reflection coefficient Γ' reflects a phase caused by a transmission line. The phase-shifted reflection coefficient Γ' may be calculated by Equation 1. The impedance processing unit 111 may calculate impedance Z_i , the reflection coefficient Γ_i , the phase-shifted reflection coefficient Γ' reflecting a phase caused by a transmission line, and the phase-shifted admittance y' .

[110] In step S124, an optimal condition for impedance matching may be determined using the phase-shifted reflection coefficient Γ' . The driving frequency control unit 113 may determine an optimal condition for impedance matching using the phase-shifted reflection coefficient Γ' . The optimum condition may be determined by a magnitude of an absolute value of the phase-shifted reflection coefficient $|\Gamma'|$ or the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient Γ' . When the determined condition is an optimal

condition, the first step S121 may be performed to measure the RF current signal I and the RF voltage signal V at the output terminal of the pulse-type variable frequency RF generator after increasing the index m indicating the processing number
5 for tuning of the driving frequency. When the determined condition is not the optimal condition, the third step S126 may be performed to vary the driving frequency.

[111] Specifically, when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient is within a threshold
10 value (or the impedance matching is completed), the first step S121 may be performed to measure the RF current signal I and the RF voltage signal V at the output terminal of the pulsed variable frequency RF generator after increasing the index m indicating the processing number for tuning of a driving
15 frequency (S124a). When the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient is out of the threshold value, the third step S126 may be performed to vary the driving frequency.

[112] In the third step S126, an increasing or decreasing
20 direction of the driving frequency of the pulsed variable frequency RF generator is selected according to a sign of the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient at the n-th ON-time period $T_{\text{ON}}(n)$ and then the frequency is varied. Specifically, when the imaginary part
25 $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a

positive value, the driving frequency is increased. Meanwhile, when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a negative value, the driving frequency is decreased. The variation amount df of the driving frequency
5 may depend on the magnitude of the absolute value of the reflection coefficient $|\Gamma'|$ or the magnitude of the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient.

[113] In step S125, a determination may be made as to whether the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse is finished. That
10 is, when $m > q$, the ON-time period $T_{\text{ON}}(n)$ is finished. When the ON-time period $T_{\text{ON}}(n)$ is not finished, in step S126, an increasing or decreasing direction of the driving frequency of the pulsed variable frequency RF generator may be selected and the driving frequency may be varied depending on the sign of
15 the imaginary part $\text{Im}(\Gamma')$ of phase-shifted reflection coefficient in the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse.
[114] The first step S121, the second step S122, S123, and the third step S126 may be repeated until the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse is finished.

20 [115] When the ON-time period $T_{\text{ON}}(n)$ is finished ($m > q$), in step S131, a driving frequency of an ON-time period $T_{\text{ON}}(n+1)$ of an $(n+1)$ -th pulse may be predicted using the admittance y' of the ON-time period $T_{\text{ON}}(n)$ of the n -th pulse. The step S131 may include linearly fitting an imaginary part of the phase-shifted
25 admittance y' in the n -th ON-time period $T_{\text{ON}}(n)$ with respect

to the driving frequency and setting a frequency corresponding to a point, in which the imaginary part of the phase-shifted admittance y' is zero (0), as a predicted driving frequency $f(n+1,1)$ of an ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse.

5 The step S131 may be selectively performed only when impedance matching is not completed.

[116] The prediction driving frequency $f(n+1, m=1)$ of the ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse may be given by Equation 3 or Equation 4. When $m=1$, a stability of plasma, a load, may be reduced due to a start time of a pulse to measure unstable impedance. Accordingly, the prediction driving frequency to be used in the ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse may be used by processing data measured in a predetermined r -th processing number and data measured in a last q -th processing number. That is, r may be a positive integer of 3 to $q-1$.

[117] After the driving frequency of the ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse is predicted, time delay may be performed for an OFF-time period T_{OFF} (S132).

20 [118] Then, for the next pulse, set $n=n+1$ and a processing number index of a control loop is set to $m=1$ (S133).

[119] Then, RF power is output at a prediction driving frequency $f(n+1,1)$ of the ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse (S141).

[120] Then, the control loop is repeated q times in the $(n+1)$ -th pulse until an $(n+2)$ -th pulse starts.

[121] Referring to FIG. 8, a pulsed variable frequency RF generator 110 provides RF power to the load 140 as an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. The pulse generator 116 generates a pulse signal of an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate. The pulse signal may have a period of about 100 μ sec.

[122] A driving frequency of the pulsed variable frequency RF generator 110 starts at a start driving frequency f_{start} of a first pulse to have a driving frequency of $f(n, m=1)$ in a control loop of $m=1$ of an n -th pulse. When an imaginary part $Im(\Gamma')$ of a phase-shifted reflection coefficient has a negative value, the driving frequency is decreased depending on time. A driving frequency $f(n+1, m=1)$ to be used in a control loop of $m=1$ of an $(n+1)$ -th pulse is predicted by using a driving frequency and susceptance b' in a control loop of $m=r$ and a control loop of $m=q$. That is, a start driving frequency of the next pulse is predicted using a driving frequency and susceptance b' of a previous pulse. Accordingly, high-speed frequency tuning impedance matching or optimum frequency setting may be completed. According to the present disclosure, impedance matching is completed within one to three pulses.

[123] Referring to FIG. 9, a variable range of the driving frequency of the pulse-type variable frequency RF generator 110

may be 12.88 MHz to 14.24 MHz. A matched frequency was 13.56 MHz and a real part of impedance Z' , including an impedance matching network 130 and a load 140, was set to 50 ohms. A phase-shifted reflection coefficient Γ' or phase-shifted admittance y' is shown on the Smith chart. An optimal impedance matching position is a frequency at which an imaginary part of the reflection coefficient Γ' is "0". On the Smith chart, susceptance b' increases from a negative value to zero as the driving frequency increases from 12.88 MHz. Meanwhile, the susceptance b' decreases from a positive value to zero as the driving frequency decreases from 14.24 MHz.

[124] In a conductance circle in which $g'=1$, as the drive frequency is increased, the susceptance b' rotates clockwise along the circle and an absolute value of the susceptance b' gradually approaches zero. When the absolute value of the susceptance b' reaches zero, impedance matching is achieved.

[125] Referring to FIGS. 10 and 11, solid line indicates susceptance b' depending on a driving frequency when a real part of impedance Z' of the impedance matching network 130 and the load 140 are 50 ohm. As the driving frequency increase from 12.88 MHz, the susceptance b' increases from a negative value to zero. $f(n,m=r)$ denotes a driving frequency of an m -th control loop in an ON-time period $T_{ON}(n)$ of an n -th pulse. f_{match} denotes a driving frequency at which impedance matches. Dotted line is straight line connecting susceptance at $f(n,m=r)$

and susceptance at $f(n, m=q)$. A frequency of a position, in which the straight line is the zero, is a predicted matching frequency expected in the ON-time period of the $(n+1)$ -th pulse. The frequency $f(n+1, m=1)$, at which the susceptance b' of the
5 straight line connecting r and q to is zero "0", is a prediction matching frequency and becomes a start driving frequency of the next pulse.

[126] When a prediction driving frequency, obtained using data (or susceptance) in an ON-time period of an n -th pulse, is used
10 as a start driving frequency of the ON-time period of an $(n+1)$ -th pulse, frequency tuning impedance matching is completed at high speed.

[127] FIG. 12 illustrates an imaginary part of admittance depending on a driving frequency according to another example
15 embodiment of the present disclosure.

[128] FIG. 13 illustrates variation of a driving frequency depending on operating time of a control loop in FIG. 12.

[129] Referring to FIGS. 12 and 13, solid line indicates susceptance b' depending on a driving frequency when a real part
20 of impedance Z' of impedance matching network and a load is 50 ohm. As the drive frequency increases from 12.88 MHz, the susceptance b' increases from a negative value to zero. $f(n, m=r)$ denotes a driving frequency of an m -th control loop in an ON-time period $T_{ON}(n)$ of an n -th pulse. f_{match} denotes
25 a driving frequency at which the impedance matches. Dotted line

is straight line connecting susceptance at $f(n, m=r)$ and the susceptance at $f(n, m=q)$. A driving frequency of a point, in which a straight line connecting r and q is zero, is a prediction driving frequency expected in an ON-time period of the $(n+1)$ -th pulse. A driving frequency, at which susceptance b' of the straight line connecting r and q is "0", is $f(n+1, 1)$. The driving frequency $f(n+1, 1)$ is greater than f_match (13.56 MHz). [130] An imaginary part $\text{Im}(\Gamma')$ of a reflection coefficient at a prediction driving frequency of an ON-time period of the $(n+1)$ -th pulse has a positive value. Therefore, in the ON-time period of the $(n+1)$ -th pulse, the driving frequency decreases as a control loop operates.

[131] When the prediction driving frequency, obtained using data (or susceptance) of an ON-time period of an n -th pulse, is used as a start driving frequency of the ON-time period of the $(n+1)$ -th pulse, frequency tuning impedance matching is completed at high speed.

[132] FIG. 14 is a Smith chart illustrating a load and variation in impedance Z' of an impedance matching network according to another example embodiment of the present disclosure.

[133] FIG. 15 is a graph illustrating susceptance, shown on the Smith chart in FIG. 14, depending on a driving frequency.

[134] Referring to FIGS. 14 and 15, a conductance circle, in which $g'=1$, is a case in which a real part $\text{Re}(Z')$ of impedance Z' is 50 ohms. A circle, in which $g'=0.5$, is a case in which

a real part $\text{Re}(Z')$ of impedance is 100 ohms. A circle, in which $g'=2$, is a case in which a real part of the impedance $\text{Re}(Z')$ of impedance is 25 ohms.

[135] A pulsed variable frequency RF generator may operate even
5 when a real part $\text{Re}(Z')$ of the impedance is not 50 ohms. That
is, impedance matching is not completed, but there is a driving
frequency at which an absolute value of a reflection coefficient
 $|\Gamma'|$ is significantly decreased. In the circle in which $g'=0.5$,
a position K is a point in which an imaginary part $\text{Im}(\Gamma')$ of
10 a reflection coefficient is zero and may be used as an optimal
frequency position, instead of an impedance matching condition.
In the circle in which $g'=2$, a position L position is the point
in which an imaginary part $\text{Im}(\Gamma')$ of a reflection coefficient
becomes zero and may be used as an optimal frequency position
15 instead of an impedance matching condition.

[136] Returning to FIG. 7, in step S124, an optimal condition
for impedance matching may be determined using the
phase-shifted reflection coefficient Γ' . The optimal
condition is determined by the absolute value $|\Gamma'|$ of the
20 phase-shifted reflection coefficient or the magnitude of the
imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection
coefficient. For example, when the absolute value of the
imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection
coefficient Γ' is less than or equal to a threshold value, the
25 optimum condition is determined. When the impedance matching

is not completed, the optima condition is determined depending on whether the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient is zero (or less than or equal to a threshold value).

[137] Accordingly, when the imaginary part $\text{Im}(\Gamma')$ of the reflection coefficient is zero, it is an optimum driving frequency in the present situation. As a result, the driving frequency may be maintained at the optimum driving frequency.

[138] On the other hand, when the real part of the impedance has a value greater than 50 ohms, an error of the predicted driving frequency may be increased. However, this error be reached by a control loop algorithm in a single pulse. When f_{match} is not reached even in the $(n+1)$ -th pulse, an algorithm for predicting a driving frequency is performed every pulse to reach the optimal driving frequency in an $(n+2)$ -th pulse.

[139] The pulsed variable frequency RF generator may operate at an optimal driving frequency by varying a driving frequency. The impedance matching network 130 is disposed between the pulsed variable frequency RF generator 110 and the load 140, and includes at least two variable reactance elements. The impedance matching network 130 changes a reactance value of the variable reactance element for complete impedance matching. Accordingly, the real part $\text{Re}(Z')$ of the impedance in the load direction may be changed to characteristic impedance Z_0 of a transmission line at an input terminal N2 of the impedance matching network 130. As a result, the impedance Z' is present

on a conductance circle, in which $g'=1$, and the pulsed variable frequency RF generator 110 may complete impedance matching.

[140] FIG. 16 illustrates a pulse sequence according to another example embodiment of the present disclosure.

5 [141] Referring to FIG. 16, before an algorithm for predicting a driving frequency of the present disclosure is performed, at least a pulse, in which an algorithm for predicting the driving frequency is not performed, may be transmitted to a load. Such a pulse may stabilize plasma through initial discharging.

10 During a plasma stabilization period, the driving frequency may operate at a predetermined start driving frequency f_{start} . A step of stabilizing plasma, including an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate, without variation of a driving frequency of the pulsed variable
15 frequency RF generator, may be included.

[142] Although the present disclosure and its advantages have been described in detail, it should be understood that various changes, substitutions and alterations can be made herein without departing from the spirit and scope of the disclosure
20 as defined by the following claims.

【CLAIMS】

【Claim 1】

A control method of a driving frequency of a pulsed variable frequency RF generator providing RF power to a load
5 as a pulse of an ON-time period T_{ON} and an OFF-time period T_{OFF} ,
which are alternate, and including a control loop varying a
driving frequency in the ON-time period T_{ON} , the control method
comprising:

varying a driving frequency $f(n,m)$ in an ON-time period
10 $T_{ON}(n)$ of an n -th pulse;

predicting a driving frequency of an ON-time period
 $T_{ON}(n+1)$ of an $(n+1)$ -th pulse using admittance of the ON-time
period $T_{ON}(n)$ of the n -th pulse; and

providing an RF output of the pulsed variable frequency
15 RF generator as the predicted driving frequency $f(n+1,1)$ in the
ON-time $T_{ON}(n+1)$ of the $(n+1)$ -th pulse,

wherein $f(n,m)$ is a driving frequency in an m -th processing
number in the ON-time period $T_{ON}(n)$ of the n -th pulse,

n denotes a sequence number of a pulse,
20 m is a positive integer of 1 to q , and

m denotes an index indicating the processing number of the
control loop for varying a driving frequency in the ON-time
period T_{ON} .

25 【Claim 2】

The control method as set forth in claim 1, wherein the varying a driving frequency $f(n,m)$ in an ON-time period $T_{ON}(n)$ of an n-th pulse comprises:

5 a first step of measuring an RF current signal I and an RF voltage signal V at an output terminal of the pulsed variable frequency RF generator in the ON-time period $T_{ON}(n)$ of the n-th pulse;

10 a second step of calculating impedance Z_i and a reflection coefficient Γ_i at the output terminal of the pulsed variable frequency RF generator by using the RF current signal I and the RF voltage signal V in the ON-time period $T_{ON}(n)$ of the n-th pulse, a phase-shifted reflection coefficient Γ' reflecting a phase caused by a transmission line, and phase-shifted admittance y' ; and

15 a third step of selecting an increasing or decreasing direction of the driving frequency of the pulsed variable frequency RF generator depending on a sign of an imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient in the ON-time period $T_{ON}(n)$ of the n-th pulse and varying the driving frequency, and

20 the first step, the second step, and the third step are repeated until the ON-time period $T_{ON}(n)$ of the n-th pulse is finished.

25 **【Claim 3】**

The control method as set forth in claim 2, wherein the predicting a driving frequency of an ON-time period $T_{ON}(n+1)$ of an $(n+1)$ -th pulse using admittance of the ON-time period $T_{ON}(n)$ of the n -th pulse comprises:

5 linearly fitting an imaginary part of the phase-shifted admittance y' in an n -th ON-time period $T_{ON}(n)$ with respect to the driving frequency; and

setting a frequency corresponding to a point, in which the imaginary part of the phase-shifted admittance y' is zero
10 (0) , as a predicted driving frequency $f(n+1,1)$ of an ON-time period $T_{ON}(n+1)$ of an $(n+1)$ -th pulse.

【Claim 4】

The control method as set forth in claim 3, wherein a
15 prediction driving frequency $f(n+1,m=1)$ of the ON-time period $T_{ON}(n+1)$ of the $(n+1)$ -th pulse is given as follows:

$$f(n+1,m=1) = f(n,m=q) - b'(n,m=q) [df/db']$$

$$df/db' = [f(n,m=q) - f(n,m=r)] / [b'(n,m=q) - b'(n,m=r)],$$

where $f(n,m=r)$ denotes a driving frequency at a
20 predetermined r -th processing number in the ON-time period $T_{ON}(n)$ of an n -th pulse,

$b'(n,m=r)$ denotes susceptance which is the imaginary part of the phase-shifted admittance y' at the predetermined r -th processing number of the ON-time period $T_{ON}(n)$ of the n -th
25 pulse,

$f(n,m=q)$ denotes a driving frequency at the last processing number in the ON-time period $T_{ON}(n)$ of the n -th pulse, and

$b'(n,m=q)$ denotes susceptance which is the imaginary part
5 of the admittance y' of the last processing number q of the ON-time period $T_{ON}(n)$ of the n -th pulse.

【Claim 5】

The control method as set forth in claim 4, wherein r is
10 a positive integer of 3 to $q-1$.

【Claim 6】

The control method as set forth in claim 2, further comprising:

15 determining an optimal condition for impedance matching using the phase-shifted reflection coefficient Γ' ,

wherein the optimal condition is determined by an absolute value $|\Gamma'|$ of the phase-shifted reflection coefficient or a magnitude of the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted
20 reflection coefficient Γ' ,

when the determined condition is the optimal condition, the first step of measuring an RF current signal I and an RF voltage signal V at an output terminal of the pulsed variable frequency RF generator is performed after increasing an index

m indicating a processing number for variation of a driving frequency, and

when the determined condition is not the optimal condition, the third step of varying the driving frequency is performed.

5

【Claim 7】

The control method as set forth in claim 2, wherein the third step of selecting an increasing or decreasing direction of the driving frequency of the pulsed variable frequency RF generator depending on a sign of an imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient in the ON-time period $T_{\text{ON}}(n)$ of the n-th pulse and varying the driving frequency comprises:

15 a driving frequency is increased when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a positive value, and

a driving frequency is decreased when the imaginary part $\text{Im}(\Gamma')$ of the phase-shifted reflection coefficient has a negative value.

20

【Claim 8】

The control method as set forth in claim 7, wherein a variation amount of the driving frequency in the n-th ON-time period $T_{\text{ON}}(n)$ depends on an absolute value of the phase-shifted

reflection coefficient or an absolute value of the imaginary part of the phase-shifted reflection coefficient.

【Claim 9】

The control method as set forth in claim 1, further
5 comprising:

changing a reactance value of a variable reactance element of an impedance matching network, which is disposed between the pulsed variable frequency RF generator and the load and includes at least two variable reactance elements, to set a real part
10 $\text{Re}(Z_i)$ of the impedance in the load direction at the output terminal of the pulsed variable frequency RF generator as characteristic impedance of a transmission line.

【Claim 10】

15 The control method as set forth in claim 1, further comprising:

a plasma stabilizing step, including an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate, without variation of the driving frequency of the pulsed variable
20 frequency RF generator.

【Claim 11】

A pulsed variable frequency RF power system comprising a pulsed variable frequency RF generator configured to supply RF

power to a load as a pulse of an ON-time period T_{ON} and an OFF-time period T_{OFF} which are alternate,

wherein the pulsed variable RF generator comprises:

an impedance sensing unit disposed at an output terminal
5 of the pulsed variable frequency RF generator in an n-th ON-time period $T_{ON}(n)$ to sense an RF current signal and an RF voltage signal;

an impedance processing unit configured to calculate impedance Z_i and a reflection coefficient Γ_i by using the RF
10 current signal and the RF voltage signal at the output terminal of the pulsed variable frequency RF generator, a phase-shifted reflection coefficient Γ' by a transmission line between the load and the pulsed variable frequency RF generator, and phase-shifted admittance y' converted from the phase-shifted
15 reflection coefficient Γ' in the n-th ON-time period $T_{ON}(n)$;

a driving frequency prediction unit configured to predict a next ON-time period $T_{ON}(n+1)$ using the phase-shifted admittance y' with respect to a driving frequency;

a driving frequency control unit configured to receive the
20 predicted driving frequency and set the predicted driving frequency as a start driving frequency of the next ON-time period $T_{ON}(n+1)$ and to control a driving frequency using the phase-shifted reflection coefficient Γ' ;

a pulse generator configured to generate a pulse signal
25 and divide the ON-time period T_{ON} and the OFF-time period T_{OFF}

and to provide the pulse signal to the driving frequency prediction unit and the driving frequency control unit; and
an RF amplifier configured to amplify a sinusoidal wave of a driving frequency of the driving frequency control unit.

5

【Claim 12】

The pulsed variable frequency RF power system as set forth in claim 11, wherein the driving frequency prediction unit linearly fits an imaginary part of phase-shifted admittance y' with respect to a driving frequency, in an n-th ON-time period $T_{ON}(n)$ to set a frequency, corresponding to a point in which the imaginary part of the phase-shifted admittance y' is zero, as a prediction driving frequency.

10